# TIL189-1 THRU TIL189-4 TIL190-1 THRU TIL190-4 OPTOCOUPLERS/OPTOISOLATORS

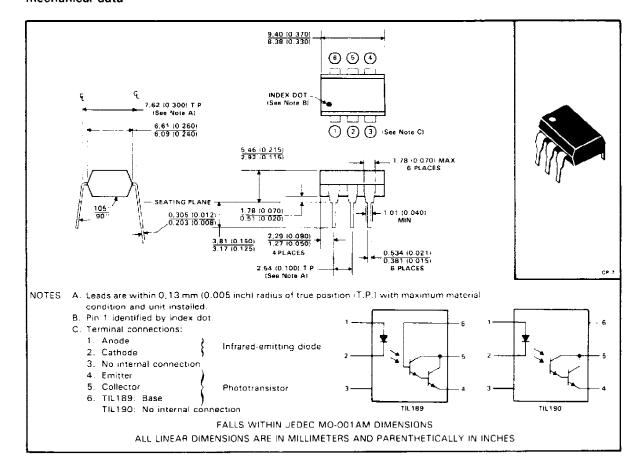
SOOS038A D2987, JANUARY 1987 - REVISED JULY 1989

- High Direct-Current Transfer Ratios, 500%
   Minimum at IF = 10 mA and Up to 1500%
   at IF = 2 mA with Choice of Four Categories
- Plastic Dual-In-Line Package
- High-Voltage Electrical Isolation, 3.535 kV Peak (2.5 kV rms)
- Gallium Arsenide Diode Infrared Source Optically Coupled to a Silicon N-P-N Darlington Phototransistor
- No Base Lead Connection on TIL190 for High-EMI Environment
- UL Recognized File #E65085

#### description

The TIL189 and TIL190 Optocouplers are designed for use in applications that require high current transfer ratio and high voltage isolation between the input and output. The TIL189 has the base connected for applications where a base signal or resistor is required. The TIL190 is designed with no internal base connection for applications where high base-noise immunity is desired. Users can select from four different current gains (TIL189-1 through TIL189-4 and TIL190-1).

#### mechanical data



# TIL189-1 THRU TIL189-4 TIL190-1 THRU TIL190-4 OPTOCOUPLERS/OPTOISOLATORS

### absolute maximum ratings at 25 °C free-air temperature (unless otherwise noted)

Input-to-output voltage
Collector-base voltage (TiL189)
Collector-emitter voltage (see Note 1)
Emitter-collector voltage
Emitter-base voltage (TIL189)
Input diode reverse voltage
Input diode continuous forward current at (or below)
25 °C free-air temperature (see Note 2)
Continuous power dissipation at (or below) 25°C free-air temperature:
Infrared-emitting diode (see Note 3)
Phototransistor (see Note 3)
Total, infrared-emitting diode plus phototransistor (see Note 4)
Storage temperature range
Lead temperature 1,6 mm (1/16-inch) from case for 10 seconds

NOTES: 1. This value applies when the base-emitter diode is open circuited.

- 2. Derate linearly to 100°C free-air temperature at the rate of 1.33 mA/°C
- 3. Derate linearly to 100°C free-air temperature at the rate of 2 mW/°C.
- 4. Derate linearly to 100 °C free-air temperature at the rate of 3.33 mW/ °C.

## electrical characteristics at 25 °C free-air temperature (unless otherwise noted)

PARAMETER  Collector-base breakdown voltage		*****	TIL189			TIL190				
		TEST CONDITIONS	MIN TYP MAX		MIN	TYP	MAX	UNIT		
		IC = 10 μA, IE = 0, IF = 0	100	•			-		٧	
Collector-emitter V(BR)CEO breakdown voltage		Ic = 1 mA, Ig = 0, IF = 0	55			66			>	
Vienceno	Emitter-base breakdown vo	pitage	$I_{E} = 10 \mu\text{A},  I_{C} = 0,$ $I_{F} = 0$	14						٧
Emitter-collector V(BR)ECO breakdown voltage		IE = 100 μA, IF = 0				7			٧	
Input diode static		VA = 3 V			10			10	μΔ	
		TIL189-1, TIL190-1		5			5			
	Photo- state transistor		$V_{CE} = 1 \text{ V}, \text{ IF} = 2 \text{ mA},$	10			10			
On-sta		TIL189-3, TIL190-3 TIL189-4, TIL190-4	3	20			20			l mA
ICton) collec	ctor operation	TIL189-4, TIL190-4		30			30			
curren	1		V <sub>CE</sub> = 1 V, I <sub>F</sub> = 10 mA, I <sub>B</sub> = 0	50			50			
Photodiode operation		de operation	$V_{CB} = 1 \text{ V}, \text{ Ip} = 10 \text{ mA}, $ $I_{E} = 0$	5	15	•				μА
Off-state collector current		$V_{CE} = 10 \text{ V, Ip} = 0,$ $I_{B} = 0$	-	1	100		1	100	nΑ	
Transistor static  hfg forward current  transfer ratio		V <sub>CE</sub> = 1 V, I <sub>C</sub> = 10 mA, I <sub>F</sub> = 0		25000						
VE	Input diode st forward volta		IF = 10 mA		1.2	1.5		1.2	1.5	٧
Collector-emitter  VCE(sat) saturation voltage		$I_C = 50 \text{ mA}, I_F = 10 \text{ mA},$ $I_B = 0$		0.87	1		0.87	1	٧	
rin	Input-to-outpu	į	V <sub>in-out</sub> = ±500 V. See Note 5	1011			1011			Ω
Cin	Input-to-outpu	ut	Vin-out = 0, f = 1 mHz, See Note 5		1	1.3		1	1.3	pF

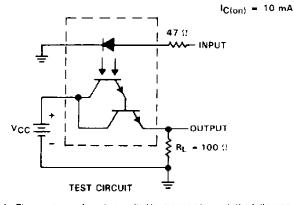
NOTE 5: These parameters are measured between both input-diode leads shorted together and all the phototransistor leads shorted together.

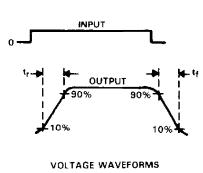
#### switching characteristics at 25°C free-air temperature

PARAMETER		TEST CONDITIONS			TIL189			TIL190		
L	- ANAINE I EN	TEST GOIDTHOUS			TYP	MAX	MIN	TYP	MAX	UNIT
tr	Rise time	V <sub>CC</sub> = 10 V,	I <sub>C(on)</sub> = 10 mA.		100			100	-	μS
t <del>f</del>	Fall time	$R_L = 100 \Omega_c$	see Figure 1		100			100		μS

#### PARAMETER MEASUREMENT INFORMATION

Adjust amplitude of input pulse for

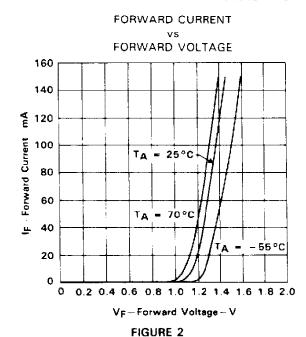


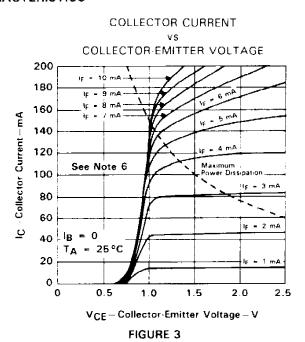


NOTES: A The input waveform is supplied by a generator with the following characteristics:  $|Z_0| = 50 \Omega$ ,  $|t_r| = \le 15$  ns, duty cycle = 1%. B. The output waveform is monitored on an oscilloscope with the following characteristics:  $|t_r| \le 12$  ns,  $|R_1| \ge 1$  M $\Omega$ ,  $|C_{10}| \le 20$  pF.

FIGURE 1. SWITCHING TIMES

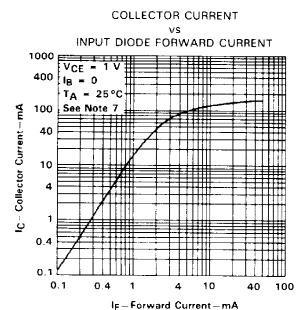
#### TYPICAL CHARACTERISTICS





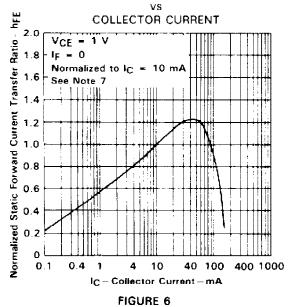
NOTE 6. Pulse operation is required for operation beyond limits shown by the dashed line.

#### TYPICAL CHARACTERISTICS

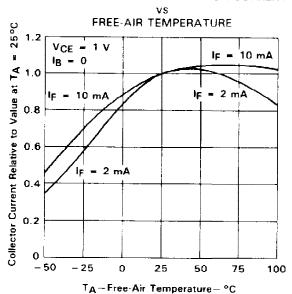


TIL189 NORMALIZED TRANSISTOR STATIC FORWARD CURRENT TRANSFER RATIO

FIGURE 4



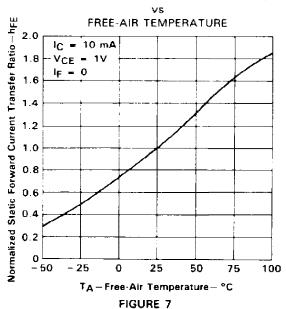
RELATIVE ON-STATE COLLECTOR CURRENT



TIL189

NORMALIZED TRANSISTOR STATIC
FORWARD CURRENT TRANSFER RATIO

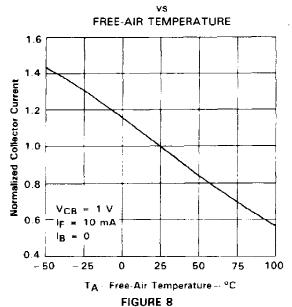
FIGURE 5



NOTE 7: These parameters were measured using pulse techniques  $t_{w} \approx 1$  ms, duty cycle  $\leq 2\%$ .

#### TYPICAL CHARACTERISTICS

# TIL189 RELATIVE ON-STATE COLLECTOR CURRENT (PHOTODIODE OPERATION)



# RELATIVE COLLECTOR-EMITTER BREAKDOWN VOLTAGE

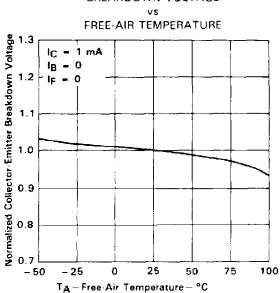
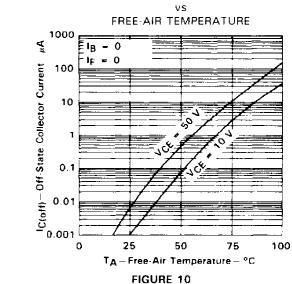


FIGURE 9

OFF-STATE COLLECTOR CURRENT



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#### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TIL189-1	OBSOLETE	PDIP	Ν	6	TBD	Call TI	Call TI
TIL189-3	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI
TIL189-4	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI
TIL190-1	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI
TIL190-2	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI
TIL190-3	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI
TIL190-4	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI

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(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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